Diode Semiconductor Device - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-330-9268

Inclosure Material:

Metal

Overall Length:

Between 12.870 inches and 13.130 inches

Function For Which Designed:

Rectifier

End Application:

E-2c hawkeye aircraft

Mounting Facility Quantity:

1

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-205ab

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 1.218 inches and 1.252 inches

Thread Size:

0.750 inches

Criticality Code Justification:

Feat

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

240.0 nonrepetitive peak reverse voltage and 200.0 working peak reverse voltage, peak total value

Current Rating Per Characteristic:

300.00 amperes forward current, average absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Weapon system essential; junction pattern arrangement: pn

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 tab, solder lug and 1 threaded stud

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

NSN 5961-01-330-9268

Diode Semiconductor Device - Page 2 of 2

Fiig: A110a0

